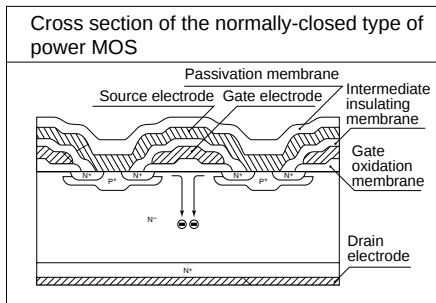
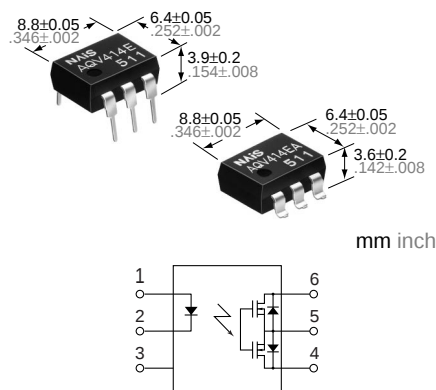


NAIS

GU (General Use)-E Type [1-Channel (Form B) Type]

PhotoMOS RELAYS



4. Low-level off state leakage current
The SSR has an off state leakage current of several milliamperes, whereas the PhotoMOS relay has only 100 pA even with the rated load voltage of 400 V (AQV414E).

5. Reinforced insulation 5,000 V type also available.
More than 0.4 mm internal insulation distance between inputs and outputs. Conforms to EN41003, EN60950 (reinforced insulation).

FEATURES

1. Low on resistance for normally-closed type

This has been realized thanks to the built-in MOSFET processed by our proprietary method, DSD (Double-diffused and Selective Doping) method.

2. Controls low-level analog signals

PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

3. High sensitivity, low ON resistance

Can control a maximum 0.13 A load current with a 5 mA input current. Low ON resistance of 18 Ω (AQV410EH). Stable operation because there are no metallic contact parts.

TYPICAL APPLICATIONS

- Security equipment
- Telepone equipment (Dial pulse)
- Measuring equipment

TYPES

Type	I/O isolation voltage	Output rating*		Part No.				Packing quantity	
				Through hole terminal	Surface-mount terminal				
		Load voltage	Load current	Tube packing style		Tape and reel packing style		Tube	Tape and reel
		Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side						
AC/DC type	1,500 V AC (Standard)	400 V	120 mA	AQV414E	AQV414EA	AQV414EAX	AQV414EAX	1 tube contains 50 pcs. 1 batch contains 500 pcs.	1,000 pcs.
	5,000 V AC (Reinforced)	350 V	130 mA	AQV410EH	AQV410EHA	AQV410EHAX	AQV410EHAZ		
		400 V	120 mA	AQV414EH	AQV414EHA	AQV414EHAX	AQV414EHAZ		

*Indicate the peak AC and DC values.

Note: For space reasons, the package type indicator "X" and "Z" are omitted from the seal.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV414E(A)	AQV410EH(A)	AQV414EH(A)	Remarks
Input	LED forward current	I _F		50 mA			f = 100 Hz, Duty factor = 0.1%
	LED reverse voltage	V _R		3 V			
	Peak forwrd current	I _{FP}		1 A			
	Power dissipation	P _{in}		75 mW			
Output	Load voltage (peak AC)	V _L		400 V	350 V	400 V	A connection: Peak AC, DC B,C connection: DC
	Continuous load current	I _L	A	0.12 A	0.13 A	0.12 A	
			B	0.13 A	0.15 A	0.13 A	
		C	0.15 A	0.17 A	0.15 A		
	Peak load current	I _{peak}		0.3 A	0.4 A	0.3 A	A connection: 100 ms (1 shot), V _L = DC
	Power dissipation	P _{out}		500 mW			
Total power dissipation		P _T		550 mW			
I/O isolation voltage		V _{iso}		1,500 V AC	5,000 V AC	5,000 V AC	
Temperature limits	Operating	T _{opr}		−40°C to +85°C −40°F to +185°F			Non-condensing at low temperatures
	Storage	T _{stg}		−40°C to +100°C −40°F to +212°F			

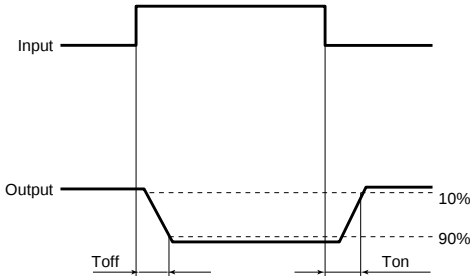
AQV414E, AQV410EH

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	Type of connection	AQV414E(A)	AQV410EH(A)	AQV414EH(A)	Condition	
Input	LED operate (OFF) current	Typical	I _{Off}	—	1.45 mA	1.9 mA	1.75 mA	I _L = Max.	
		Maximum			3.0 mA				
	LED reverse (ON) current	Minimum	I _{Fon}	—	0.3 mA	0.4 mA	0.3 mA	I _L = Max.	
		Typical			1.40 mA	1.8 mA	1.70 mA		
	LED dropout voltage	Typical	V _F	—	1.14 V (1.25 V at I _F = 50 mA)			I _F = 5 mA	
Maximum		1.5 V							
Output	On resistance	Typical	R _{on}	A	26 Ω	18 Ω	25.2 Ω	I _F = 0 mA I _L = Max. Within 1 s on time	
		Maximum			50 Ω	35 Ω	50 Ω		
		Typical	R _{on}	B	20 Ω	13 Ω	19 Ω	I _F = 0 mA I _L = Max. Within 1 s on time	
		Maximum			25 Ω	17.5 Ω	25 Ω		
		Typical	R _{on}	C	10 Ω	6.5 Ω	10 Ω	I _F = 0 mA I _L = Max. Within 1 s on time	
		Maximum			12.5 Ω	8.8 Ω	12.5 Ω		
	Off state leakage current	Maximum	I _{Leak}	—	1 μA	10 μA	10 μA	I _F = 5 mA V _L = Max.	
Transfer characteristics	Switching speed	Operate (OFF) time*	Typical	T _{off}	—	0.7 ms	1.5 ms	1.3 ms	I _F = 0 mA → 5 mA I _L = Max.
			Maximum			2.0 ms	3.0 ms	3.0 ms	
		Reverse (ON) time*	Typical	T _{on}	—	0.1 ms	0.3 ms	0.3 ms	I _F = 5 mA → 0 mA I _L = Max.
			Maximum			1.0 ms	1.5 ms	1.5 ms	
	I/O capacitance		Typical	C _{iso}	—	0.8 pF	0.8 pF	0.8 pF	f = 1 MHz V _B = 0
			Maximum			1.5 pF			
	Initial I/O isolation resistance		Minimum	R _{iso}	—	1,000 MΩ			500 V DC

Note: Recommendable LED forward current
Standard type I_F = 5 mA
Reinforced type I_F = 5 to 10 mA
*Operate/Reverse time

For type of connection, see Page 32.



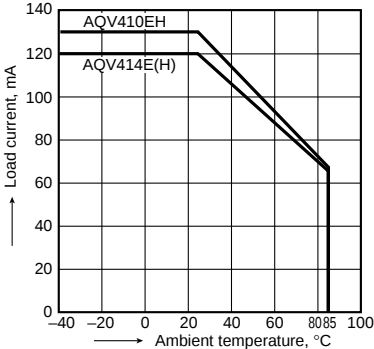
- For Dimensions, see Page 27.
- For Schematic and Wiring Diagrams, see Page 32.
- For Cautions for Use, see Page 36.

REFERENCE DATA

1. Load current vs. ambient temperature characteristics

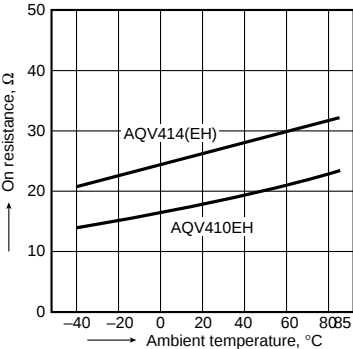
Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F

Type of connection: A



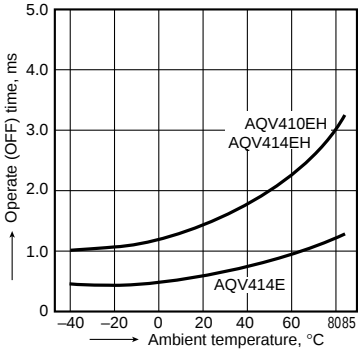
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
LED current: 0 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



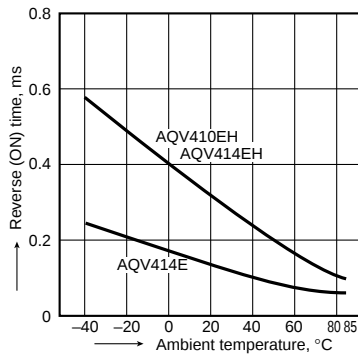
3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



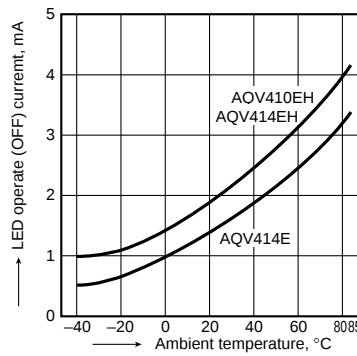
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



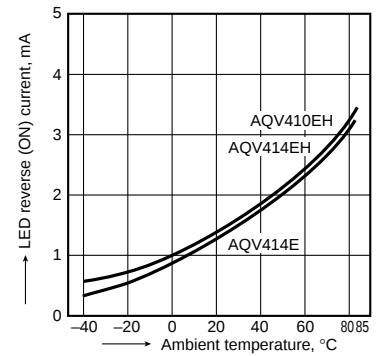
5. LED operate (OFF) current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



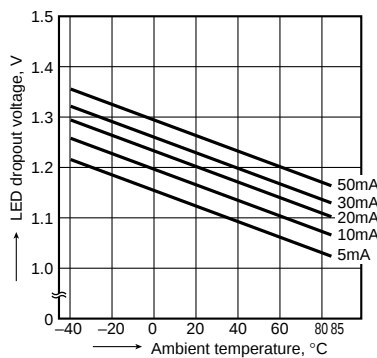
6. LED reverse (ON) current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



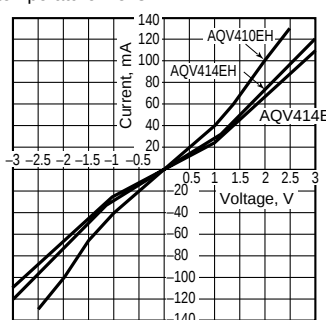
7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



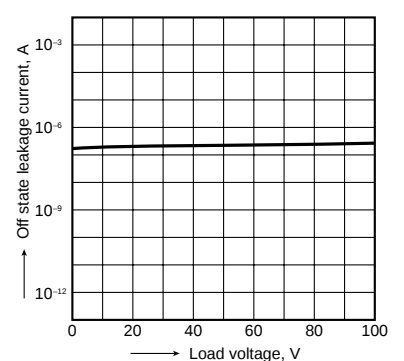
8. Voltage vs. current characteristics of output at MOS portion

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



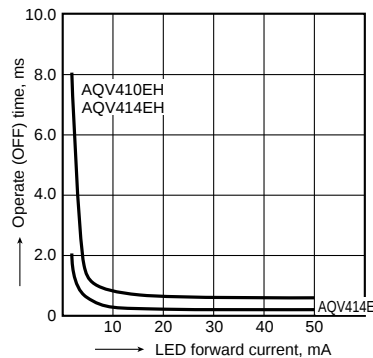
9. Off state leakage current

Measured portion: between terminals 4 and 6;
LED current: 5 mA; Ambient temperature: 25°C 77°F



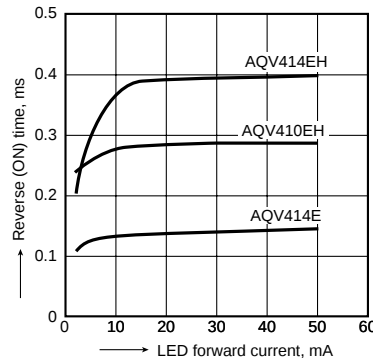
10. LED forward current vs. operate (OFF) time characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



11. LED forward current vs. reverse (ON) time characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



12. Applied voltage vs. output capacitance characteristics

Measured portion: between terminals 4 and 6;
Frequency: 1 MHz;
Ambient temperature: 25°C 77°F

